

# Interference Search

## EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	19	((strained or strain or straining) near (SOI or silicon-on-insulator) or ssoi or ssdoi).clm.	US-PGPUB	OR	ON	2006/05/26 09:51
L2	35	((SOI or silicon-on-insulator or buried near insulator or buried near oxide or box) and (straining or strain near (inducing or induced or applying or application or applied or transfer\$4 or impress\$4))).clm.	US-PGPUB	OR	ON	2006/05/26 09:49
L3	10	((SOI or silicon-on-insulator or buried near insulator or buried near oxide or box) and (straining or strain near (inducing or induced or applying or application or applied or transfer\$4 or impress\$4)) near6 (sige or si near ge or gesi or silicon near germanium)).clm.	US-PGPUB	OR	ON	2006/05/26 09:50
L4	33	((straining or strain near (inducing or induced or applying or application or applied or transfer\$4 or impress\$4)) near4 (heat or heating or heated or anneal\$4 or thermal or thermally or rta or temperature)).clm.	US-PGPUB	OR	ON	2006/05/26 09:51
L6	166	((strained or strain or straining) near (SOI or silicon-on-insulator) or ssoi or ssdoi or ((strained or tensile or compressive or straining or strain) near3 (silicon or si) and (buried near oxide or box or buried near insulator or soi or silicon-on-insulator))).clm.	US-PGPUB	OR	ON	2006/05/26 09:53
L7	37	L6 and ((strain or straining or strained or lattice or tensile or compressive or compression or relaxation or relaxed) near8 (anneal\$4 or heat or heating or heated or thermal or thermally or temperature or rta)).clm.	US-PGPUB	OR	ON	2006/05/26 09:54